

NCP553, NCV553

Voltage Regulator - CMOS, Low Iq, NOCAPE

80 mA

This series of fixed output NOCAP linear regulators are designed for handheld communication equipment and portable battery powered applications which require low quiescent. This series features an ultra-low quiescent current of 2.8 μ A. Each device contains a voltage reference unit, an error amplifier, a PMOS power transistor, resistors for setting output voltage, current limit, and temperature limit protection circuits.

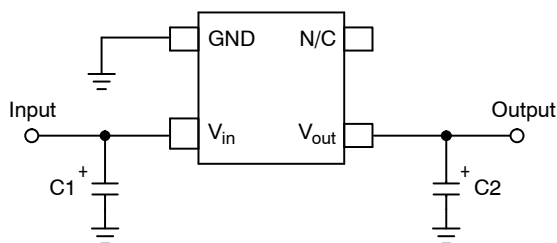
These voltage regulators have been designed to be used with low cost ceramic capacitors. The devices have the ability to operate without an output capacitor. The devices are housed in the micro-miniature SC82-AB surface mount package. Standard voltage versions are 1.5, 1.8, 2.5, 2.7, 2.8, 3.0, 3.3, and 5.0 V. Other voltages are available in 100 mV steps.

Features

- Low Quiescent Current of 2.8 μ A Typical
- Low Output Voltage Option
- Output Voltage Accuracy of 2.0%
- Industrial Temperature Range of -40°C to 85°C
(NCV553, $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$)
- These are Pb-Free Devices
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

Typical Applications

- Battery Powered Consumer Products
- Hand-Held Instruments
- Camcorders and Cameras



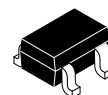
This device contains 32 active transistors

Figure 1. Typical Application Diagram



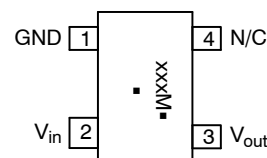
ON Semiconductor®

<http://onsemi.com>



SC82-AB (SC70-4)
SQ SUFFIX
CASE 419C

PIN CONNECTIONS & MARKING DIAGRAMS



(NCP553, NCV553 Top View)

xxx = Device Code
M = Date Code⁸
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

NCP553, NCV553

PIN FUNCTION DESCRIPTION

Pin	Pin Name	Description
1	GND	Power supply ground.
2	V _{in}	Positive power supply input voltage.
3	V _{out}	Regulated output voltage.
–	Enable	This input is used to place the device into low-power standby. When this input is pulled low, the device is disabled. If this function is not used, Enable should be connected to V _{in} .
4	N/C	No internal connection.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V _{in}	12	V
Output Voltage	V _{out}	–0.3 to V _{in} +0.3	V
Power Dissipation and Thermal Characteristics Power Dissipation Thermal Resistance, Junction-to-Ambient	P _D R _{θJA}	Internally Limited 400	W °C/W
Operating Junction Temperature	T _J	+125	°C
Operating Ambient Temperature NCP553 NCV553	T _A	–40 to +85 –40 to +125	°C
Storage Temperature	T _{stg}	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. This device series contains ESD protection and exceeds the following tests:

Human Body Model 2000 V per MIL-STD-883, Method 3015

Machine Model Method 200 V

2. Latch up capability (85°C) ±200 mA DC with trigger voltage.

NCP553, NCV553

ELECTRICAL CHARACTERISTICS

($V_{in} = V_{out(nom.)} + 1.0\text{ V}$, $V_{enable} = V_{in}$, $C_{in} = 1.0\ \mu\text{F}$, $C_{out} = 1.0\ \mu\text{F}$, $T_J = 25^\circ\text{C}$, unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage ($T_A = 25^\circ\text{C}$, $I_{out} = 10\text{ mA}$) 1.5 V 1.8 V 2.5 V 2.7 V 2.8 V 3.0 V 3.3 V 5.0 V	V_{out}	1.455 1.746 2.425 2.646 2.744 2.94 3.234 4.900	1.5 1.8 2.5 2.7 2.8 3.0 3.3 5.0	1.545 1.854 2.575 2.754 2.856 3.06 3.366 5.100	V
Output Voltage ($T_A = -40^\circ\text{C}$ to 85°C , $I_{out} = 10\text{ mA}$) 1.5 V 1.8 V 2.5 V 2.7 V 2.8 V 3.0 V 3.3 V 5.0 V	V_{out}	1.455 1.746 2.425 2.619 2.716 2.910 3.201 4.900	1.5 1.8 2.5 2.7 2.8 3.0 3.3 5.0	1.545 1.854 2.575 2.781 2.884 3.09 3.399 5.100	V
Output Voltage ($T_A = -40^\circ\text{C}$, $I_{out} = 10\text{ mA}$) NCV553 -5.0 V	V_{out}	4.900	5.0	5.100	V
Output Voltage ($T_A = +125^\circ\text{C}$, $I_{out} = 10\text{ mA}$) NCV553 -5.0 V	V_{out}	4.850	5.0	5.150	V
Line Regulation ($V_{in} = V_{out} + 1.0\text{ V}$ to 12 V , $I_{out} = 10\text{ mA}$)	Reg_{line}	-	2.0	4.5	mV/V
Load Regulation ($I_{out} = 1.0\text{ mA}$ to 80 mA , $V_{in} = V_{out} + 2.0\text{ V}$)	Reg_{load}	-	0.3	0.8	mV/mA
Output Current ($V_{out} = (V_{out}$ at $I_{out} = 80\text{ mA}) - 3.0\%$) 1.5 V-3.9 V ($V_{in} = V_{out(nom.)} + 2.0\text{ V}$) 4.0 V-5.0 V ($V_{in} = 6.0\text{ V}$)	$I_{o(nom.)}$	80 80	180 180	- -	mA
Dropout Voltage ($T_A = -40^\circ\text{C}$ to 125°C , $I_{out} = 80\text{ mA}$, Measured at $V_{out} - 3.0\%$) 1.5 V 1.8 V 2.5 V 2.7 V 2.8 V 3.0 V 3.3 V 5.0 V	$V_{in} - V_{out}$	- - - - - - - -	1300 1100 800 750 730 680 650 470	1800 1600 1400 1200 1200 1000 1000 800	mV
Quiescent Current (Enable Input = 0 V) (Enable Input = V_{in} , $I_{out} = 1.0\text{ mA}$ to $I_{o(nom.)}$, $V_{in} = V_{out} + 2.0\text{ V}$)	I_Q	- -	0.1 2.8	1.0 6.0	μA
Output Short Circuit Current ($V_{out} = 0\text{ V}$) 1.5 V-3.9 V ($V_{in} = V_{out(nom.)} + 2.0\text{ V}$) 4.0 V-5.0 V ($V_{in} = 6.0\text{ V}$)	$I_{out(max)}$	100 100	300 300	450 450	mA
Output Voltage Noise ($f = 20\text{ Hz}$ to 100 kHz , $I_{out} = 10\text{ mA}$) ($C_{out} = 1.0\ \mu\text{F}$)	V_n	-	90	-	μVrms
Output Voltage Temperature Coefficient	T_C	-	± 100	-	ppm/ $^\circ\text{C}$

3. Maximum package power dissipation limits must be observed.

$$PD = \frac{T_J(max) - T_A}{R_{\theta JA}}$$

4. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

DEFINITIONS

Load Regulation

The change in output voltage for a change in output current at a constant temperature.

Dropout Voltage

The input/output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 3.0% below its nominal. The junction temperature, load current, and minimum input supply requirements affect the dropout level.

Maximum Power Dissipation

The maximum total dissipation for which the regulator will operate within its specifications.

Quiescent Current

The quiescent current is the current which flows through the ground when the LDO operates without a load on its output: internal IC operation, bias, etc. When the LDO becomes loaded, this term is called the Ground current. It is actually the difference between the input current (measured through the LDO input pin) and the output current.

Line Regulation

The change in output voltage for a change in input voltage. The measurement is made under conditions of low dissipation or by using pulse technique such that the average chip temperature is not significantly affected.

Line Transient Response

Typical over and undershoot response when input voltage is excited with a given slope.

Thermal Protection

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated at typically 160°C, the regulator turns off. This feature is provided to prevent failures from accidental overheating.

Maximum Package Power Dissipation

The maximum power package dissipation is the power dissipation level at which the junction temperature reaches its maximum operating value, i.e. 125°C. Depending on the ambient power dissipation and thus the maximum available output current.

TYPICAL CHARACTERISTICS

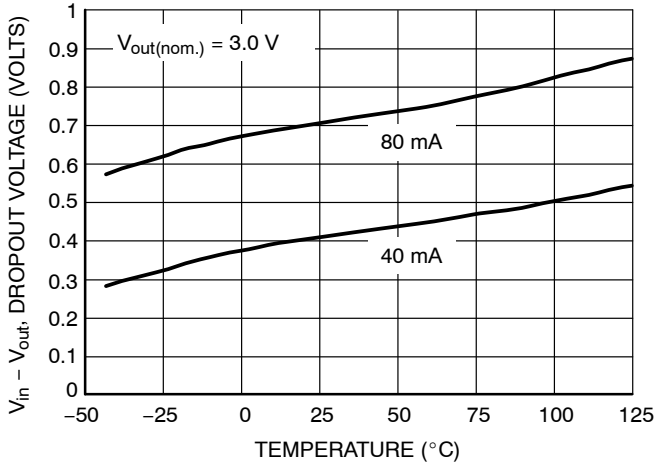


Figure 2. Dropout Voltage versus Temperature

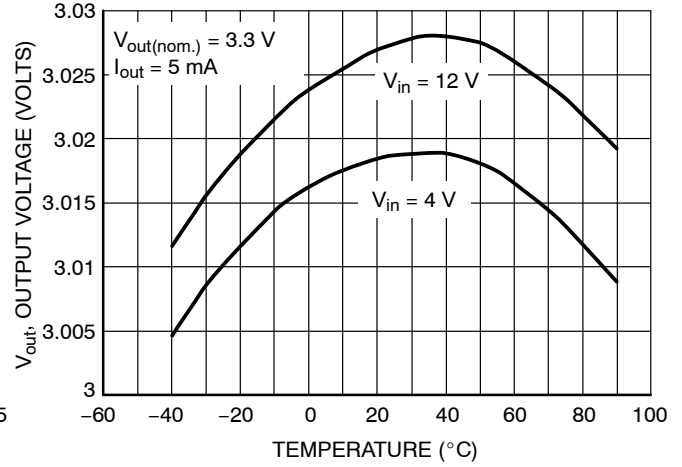


Figure 3. Output Voltage versus Temperature

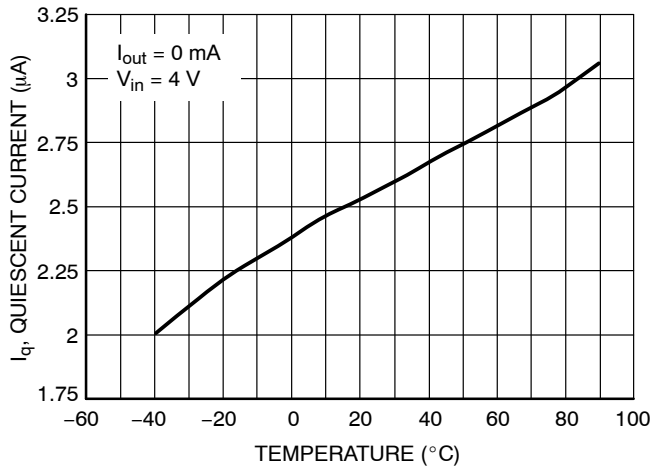


Figure 4. Quiescent Current versus Temperature

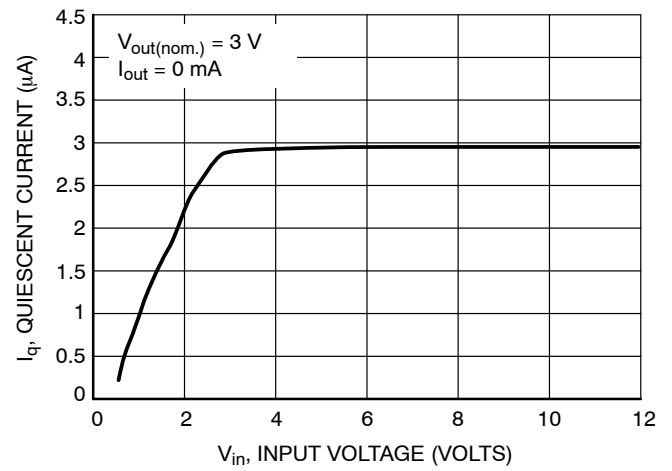


Figure 5. Quiescent Current versus Input Voltage

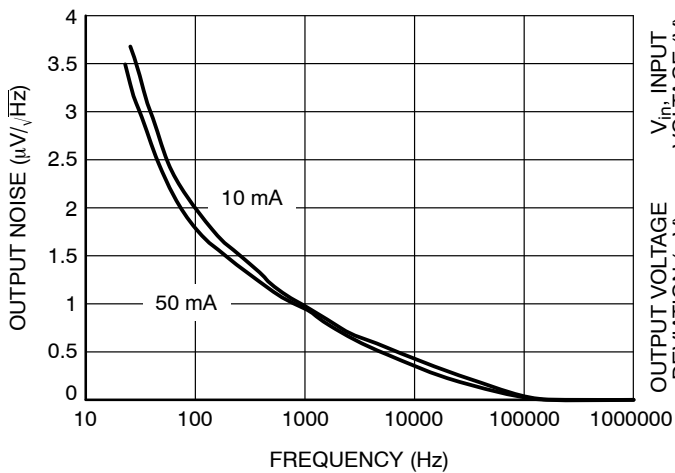


Figure 6. Output Noise Density

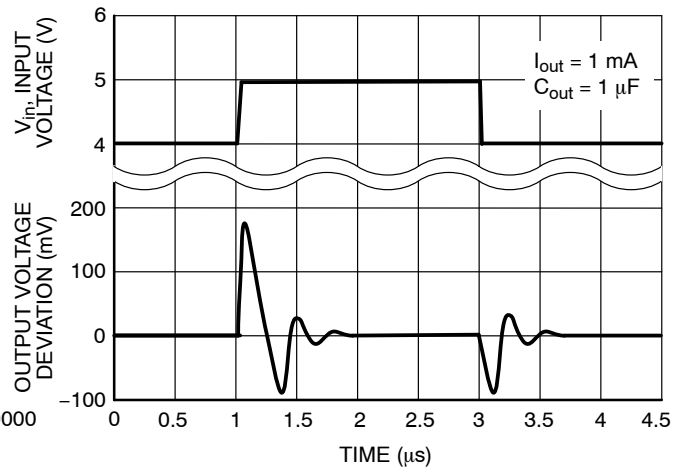


Figure 7. Line Transient Response

NCP553, NCV553

TYPICAL CHARACTERISTICS

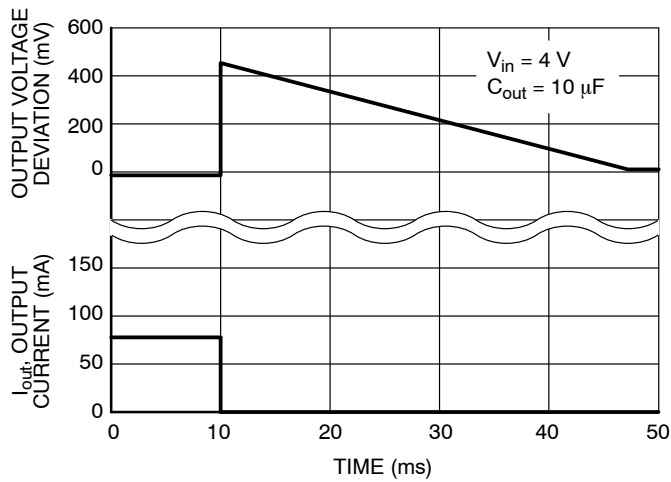


Figure 8. Load Transient Response

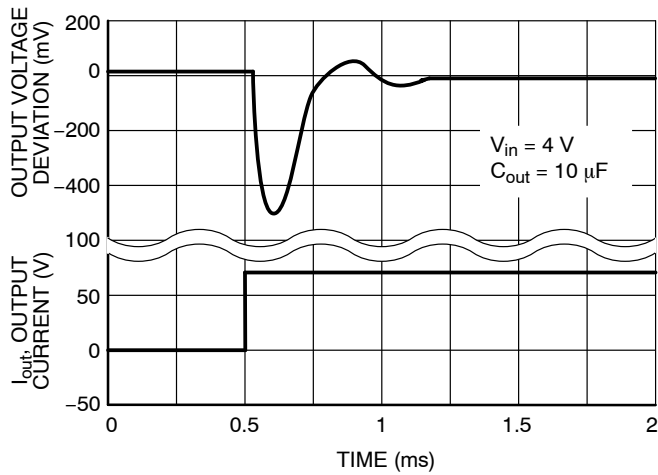


Figure 9. Load Transient Response

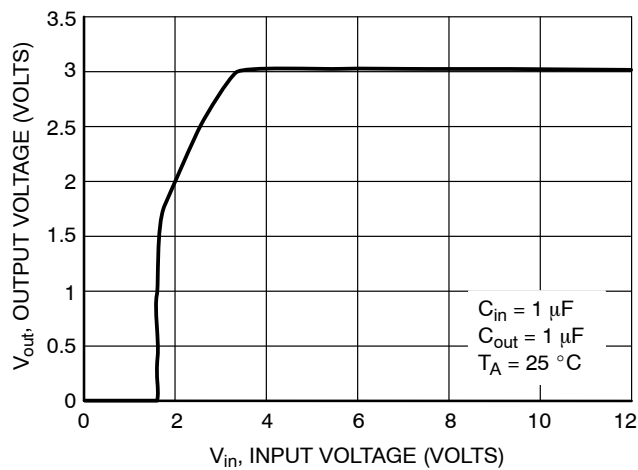


Figure 10. Output Voltage versus Input Voltage

NCP553, NCV553

APPLICATIONS INFORMATION

A typical application circuit for the NCP553 series is shown in Figure 1, front page.

Input Decoupling (C1)

A 1.0 μF capacitor either ceramic or tantalum is recommended and should be connected close to the package. Higher values and lower ESR will improve the overall line transient response. If large line or load transients are not expected, then it is possible to operate the regulator without the use of a capacitor.

TDK capacitor: C2012X5R1C105K, or C1608X5R1A105K

Output Decoupling (C2)

The NCP553 are very stable regulators and do not require any specific Equivalent Series Resistance (ESR) or a minimum output current. If load transients are not to be expected, then it is possible for the regulator to operate with no output capacitor. Otherwise, capacitors exhibiting ESRs ranging from a few $\text{m}\Omega$ up to $10\ \Omega$ can thus safely be used. The minimum decoupling value is $0.1\ \mu\text{F}$ and can be augmented to fulfill stringent load transient requirements. The regulator accepts ceramic chip capacitors as well as tantalum devices. Larger values improve noise rejection and load regulation transient response.

TDK capacitor: C2012X5R1C105K, C1608X5R1A105K, or C3216X7R1C105K

Hints

Please be sure the V_{in} and GND lines are sufficiently wide. When the impedance of these lines is high, there is a chance to pick up noise or cause the regulator to malfunction.

Set external components, especially the output capacitor, as close as possible to the circuit, and make leads as short as possible.

Thermal

As power across the NCP553 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material and also the ambient temperature effect the rate of temperature rise for the part. This is stating that when the devices have good thermal conductivity through the PCB, the junction temperature will be relatively low with high power dissipation applications.

The maximum dissipation the package can handle is given by:

$$P_D = \frac{T_{J(\text{max})} - T_A}{R_{\theta JA}}$$

If junction temperature is not allowed above the maximum 125°C , then the NCP553 can dissipate up to $250\ \text{mW}$ @ 25°C .

The power dissipated by the NCP553 can be calculated from the following equation:

$$P_{\text{tot}} = [V_{in} * I_{\text{gnd}}(\text{out})] + [V_{in} - V_{out}] * I_{\text{out}}$$

or

$$V_{in\text{MAX}} = \frac{P_{\text{tot}} + V_{out} * I_{\text{out}}}{I_{\text{gnd}} + I_{\text{out}}}$$

If an $80\ \text{mA}$ output current is needed then the ground current from the data sheet is $2.8\ \mu\text{A}$. For an NCP553 ($3.0\ \text{V}$), the maximum input voltage will then be $6.12\ \text{V}$.

ORDERING INFORMATION

Device	Nominal Output Voltage (Note 5)	Marking	Package	Shipping [†]
NCP553SQ15T1G	1.5	LBE	SC82-AB (SC70-4) (Pb-Free)	3000 Units/ 8" Tape & Reel
NCP553SQ18T1G	1.8	LBF		
NCP553SQ25T1G	2.5	LBG		
NCP553SQ27T1G	2.7	LBH		
NCP553SQ28T1G	2.8	LBI		
NCP553SQ30T1G	3.0	LBJ		
NCP553SQ33T1G	3.3	LBK		
NCP553SQ50T1G	5.0	LBL		
NCV553SQ15T1G*	1.5	AAF		
NCV553SQ30T1G*	3.0	LBJ		
NCV553SQ50T1G*	5.0	LFT		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

5. Additional voltages in 100 mV steps are available upon request by contacting your ON Semiconductor representative.

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

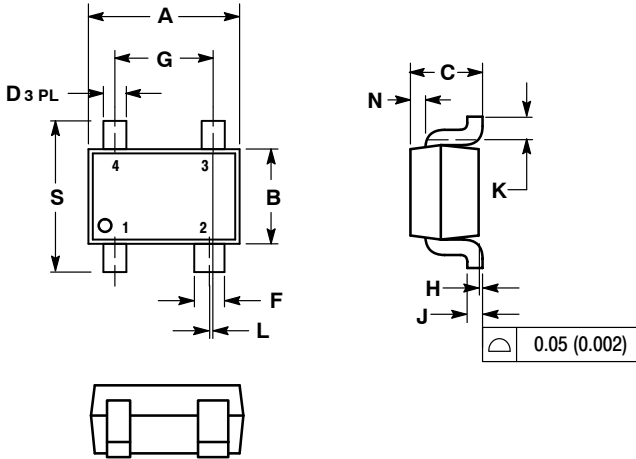
ON Semiconductor®



SC-82AB
CASE 419C-02
ISSUE F

DATE 22 JUN 2012

SCALE 4:1



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. 419C-01 OBSOLETE. NEW STANDARD IS 419C-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.80	2.20	0.071	0.087
B	1.15	1.35	0.045	0.053
C	0.80	1.10	0.031	0.043
D	0.20	0.40	0.008	0.016
F	0.30	0.50	0.012	0.020
G	1.10	1.50	0.043	0.059
H	0.00	0.10	0.000	0.004
J	0.10	0.26	0.004	0.010
K	0.10	---	0.004	---
L	0.05 BSC		0.002 BSC	
N	0.20 REF		0.008 REF	
S	1.80	2.40	0.07	0.09

SOLDERING FOOTPRINT*



GENERIC MARKING DIAGRAM*



- XXX = Specific Device Code
- M = Month Code
- = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98ARB18939C	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SC-82AB	PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support:
Voice Mail: 1 800-282-9855 Toll Free USA/Canada
Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative